

# HMC386LP4 / 386LP4E

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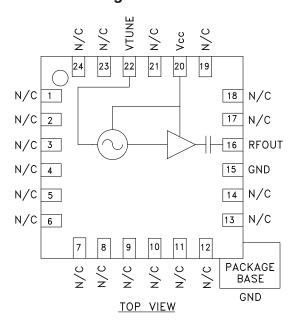
MMIC VCO w/ BUFFER AMPLIFIER, 2.6 - 2.8 GHz

### Typical Applications

Low noise MMIC VCO w/Buffer Amplifier for:

- Wireless Infrastructure
- Industrial Controls
- Test Equipment
- Military

## **Functional Diagram**



#### **Features**

Pout: +5 dBm

Phase Noise: -114 dBc/Hz @100 kHz No External Resonator Needed

Single Supply: 3V @ 35mA

24 Lead 4x4mm QFN Package: 16 mm²

### **General Description**

The HMC386LP4 & HMC386LP4E are GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCOs with integrated resonators, negative resistance devices, varactor diodes, and buffer amplifiers. Covering 2.6 to 2.8 GHz, the VCO's phase noise performance is excellent over temperature, shock, vibration and process due to the oscillator's monolithic structure. Power output is 5 dBm typical from a single supply of 3V @ 35mA. The voltage controlled oscillator is packaged in a low cost leadless QFN 4x4 mm surface mount package.

## Electrical Specifications, $T_{\Delta} = +25$ °C, Vcc = +3V

Parameter	Min.	Тур.	Max.	Units
Frequency Range	2.6 - 2.8			GHz
Power Output	2	5		dBm
SSB Phase Noise @ 100 kHz Offset, Vtune = +5V @ RF Output		-114		dBc/Hz
Tune Voltage (Vtune)	0		10	V
Supply Current (Icc) (Vcc = +3V)		35		mA
Tune Port Leakage Current			10	μΑ
Output Return Loss		9		dB
Harmonics 2nd 3rd		-5 -15		dBc dBc
Pulling (into a 2.0:1 VSWR)		3		MHz pp
Pushing @ Vtune = +5V		2		MHz/V
Frequency Drift Rate		0.3		MHz/°C

# **HMC386\* PRODUCT PAGE QUICK LINKS**

Last Content Update: 02/23/2017

## COMPARABLE PARTS -

View a parametric search of comparable parts.

## **EVALUATION KITS**

· HMC386LP4 Evaluation Board

## **DOCUMENTATION**

#### **Application Notes**

 Determining the FM Bandwidth of a Wideband Varactor Tuned VCO

#### **Data Sheet**

· HMC386 Data Sheet

## REFERENCE MATERIALS 🖳

#### **Quality Documentation**

- Package/Assembly Qualification Test Report: LP4, LP4B, LP4C, LP4K (QTR: 2013-00487 REV: 04)
- Package/Assembly Qualification Test Report: Plastic Encapsulated QFN (QTR: 05006 REV: 02)
- Semiconductor Qualification Test Report: GaAs HBT-A (QTR: 2013-00228)

## **DESIGN RESOURCES**

- HMC386 Material Declaration
- PCN-PDN Information
- · Quality And Reliability
- Symbols and Footprints

### **DISCUSSIONS**

View all HMC386 EngineerZone Discussions.

## SAMPLE AND BUY 🖵

Visit the product page to see pricing options.

## **TECHNICAL SUPPORT**

Submit a technical question or find your regional support number.

### DOCUMENT FEEDBACK $\Box$

Submit feedback for this data sheet.

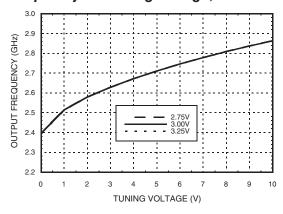


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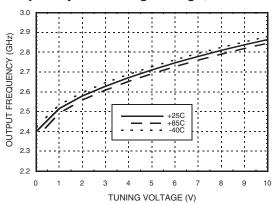


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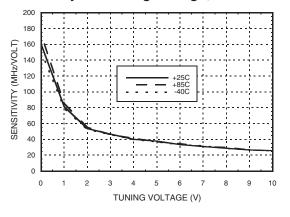
#### Frequency vs. Tuning Voltage, T = 25°C



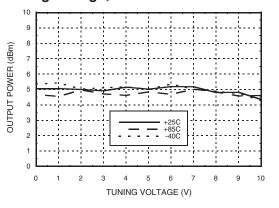
#### Frequency vs. Tuning Voltage, Vcc = +3V



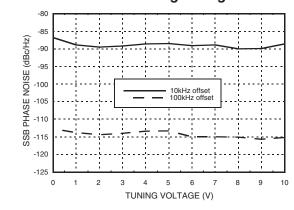
#### Sensitivity vs. Tuning Voltage, Vcc = +3V



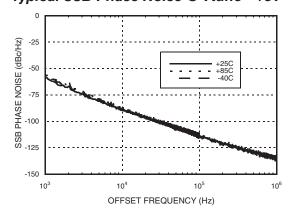
Output Power vs.
Tuning Voltage, Vcc = +3V



### Phase Noise vs. Tuning Voltage



Typical SSB Phase Noise @ Vtune= +5V





## MMIC VCO w/ BUFFER AMPLIFIER, 2.6 - 2.8 GHz

### **Absolute Maximum Ratings**

Vcc	+3.5V
Vtune	0 to +11V
Channel Temperature	135 °C
Thermal Resistance (R <sub>TH</sub> ) (junction to package base)	138 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

### Typical Supply Current vs. Vcc

Vcc (V)	Icc (mA)
2.75	30
3.0	35
3.25	40

Note: VCO will operate over full voltage range shown above.



ELECTROSTATIC SENSITIVE DEVICE **OBSERVE HANDLING PRECAUTIONS** 

### **Outline Drawing**

#### **BOTTOM VIEW** PIN 24 —.016 [0.40] REF 0.30 .008 [0.20] MIN PIN 1 HNNN XXXX 13 EXPOSED GROUND PADDLE LOT NUMBER 2.95 2.65 MUST BE CONNECTED TO RF/DC GROUND SQUARE 0.05 .002 1. LEADFRAME MATERIAL: COPPER ALLOY **SEATING** PLANE ☐ .003[0.08] C

- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM. PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOT FOR SUGGESTED LAND PATTERN.

## Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC386LP4	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H386 XXXX
HMC386LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	<u>H386</u> XXXX

-C-

- [1] Max peak reflow temperature of 235 °C
- [2] Max peak reflow temperature of 260 °C
- [3] 4-Digit lot number XXXX



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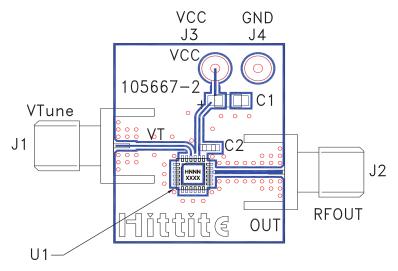


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### **Pin Descriptions**

Pin Number	Function	Description	Interface Schematic
1- 14, 17 - 19, 21, 23, 24	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
15	GND	This pin must be connected to RF & DC ground. Package bottom has an exposed metal paddle that must be RF & DC grounded.	⊖ GND =
16	RFOUT	RF output (AC coupled)	—   —○ RFOUT
20	Vcc	Supply Voltage Vcc= 3V	Vcc O26pF
22	VTUNE	Control Voltage Input. Modulation port bandwidth dependent on drive source impedance.	VTUNE 0 1500 4.6pF

#### **Evaluation PCB**



#### List of Materials for Evaluation PCB 105706 [1]

Item	Description
J1 - J2	PCB Mount SMA RF Connector
J3 - J4	DC Pin
C1	4.7 μF Tantalum Capacitor
C2	10,000 pF Capacitor, 0603 Pkg.
U1	HMC386LP4 / HMC386LP4E VCO
PCB [2]	105667 Eval Board

- [1] Reference this number when ordering complete evaluation PCB  $\,$
- [2] Circuit Board Material: Rogers 4350 or Arlon 25FR

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.